

Dual P-Channel 2.5-V (G-S) MOSFET

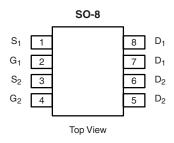
PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
- 20	$0.032 \text{ at V}_{GS} = -4.5 \text{ V}$	- 6.5		
	$0.050 \text{ at V}_{GS} = -2.5 \text{ V}$	- 5.2		

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- Compliant to RoHS Directive 2002/95/EC

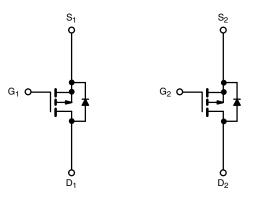






Ordering Information: Si4963BDY-T1-E3 (Lead (Pb)-free)

Si4963BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted					
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	- 20		V
Gate-Source Voltage		V _{GS}	± 12		
Continuous Drain Current /T 150 °C\2	T _A = 25 °C	I-	- 6.5	- 4.9	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C	I _D	- 5.2	- 3.9	1 ,
Pulsed Drain Current		I _{DM}	- 40		A
Continuous Source Current (Diode Conduction) ^a	I _S	- 1.7	- 0.9		
Mariana Barra Biraira di	T _A = 25 °C	D_	2.0	1.1	W
Maximum Power Dissipation ^a	T _A = 70 °C	- P _D	1.3	0.7	7
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mariana haratian ta Ankinda	t ≤ 10 s	R _{thJA}	58	62.5	
Maximum Junction-to-Ambient ^a	Steady State	□thJA	91	110	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	34	40	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

For SPICE model information via the Worldwide Web: http://www.vishay.com/www/product/spice.htm.

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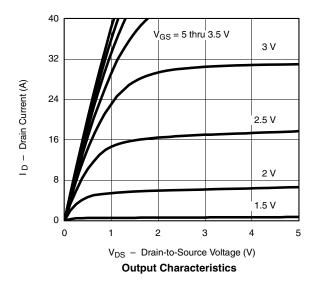
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static				1			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.6		- 1.4	V	
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 12 V			± 100	nA	
Zava Cata Valtana Dusin Comment	_	V _{DS} = - 20 V, V _{GS} = 0 V			- 1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			- 5	μΑ	
On-State Drain Current ^a	State Drain Current ^a $I_{D(on)}$ $V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$		- 20			Α	
	C	V _{GS} = - 4.5 V, I _D = - 6.5 A		0.025	0.032	0	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 2 A		0.040	0.050	Ω	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 6.5 A		18		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 1.7 A, V _{GS} = 0 V		- 0.75	- 1.2	٧	
Dynamic ^b				•			
Total Gate Charge	Q_g			14	21		
Gate-Source Charge	Q_{gs}	V _{DS} = - 10 V, V _{GS} = - 4.5 V, I _D = - 6.5 A		2.6		nC	
Gate-Drain Charge	Q _{gd}			4.6			
Gate Resistance	R_g	f = 1 MHz		8.3		Ω	
Turn-On Delay Time	t _{d(on)}			30	45		
Rise Time	t _r	V_{DD} = - 10 V, R_L = 10 Ω		40	60		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ - 1 A, V_{GEN} = - 4.5 V, R_g = 6 Ω		80	120	ns	
Fall Time	t _f			55	85		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.7 A, dl/dt = 100 A/μs		40	80		

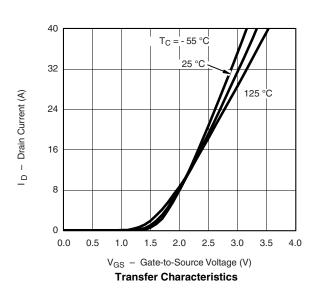
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C unless otherwise noted



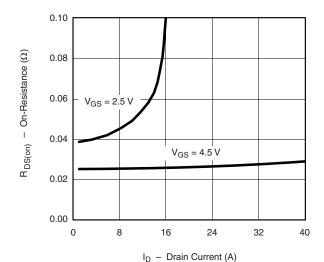


www.vishay.com Document Number: 72753 S09-0704-Rev. B, 27-Apr-09

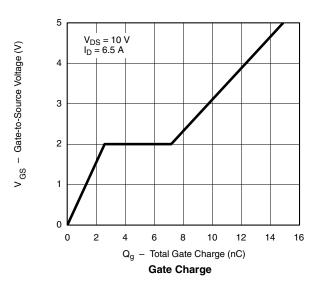


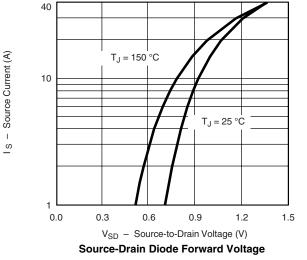


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On-Resistance vs. Drain Current

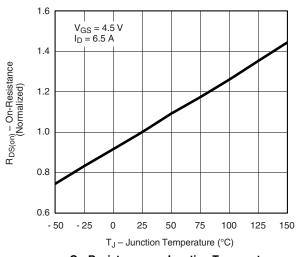




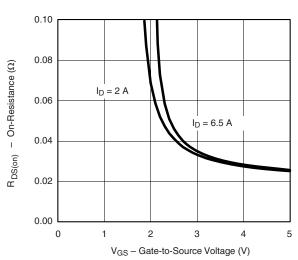
2000
1600
1600
1200
C_{iss}
C_{oss}
0
0
400
0
4
8
12
16
20

V_{DS} - Drain-to-Source Voltage (V)

Capacitance



On-Resistance vs. Junction Temperature

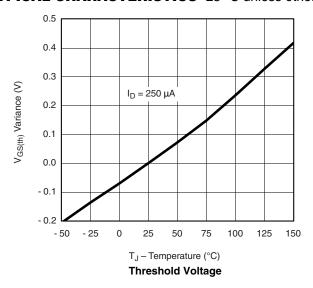


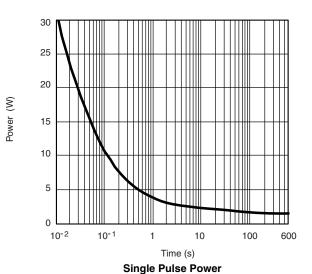
On-Resistance vs. Gate-to-Source Voltage

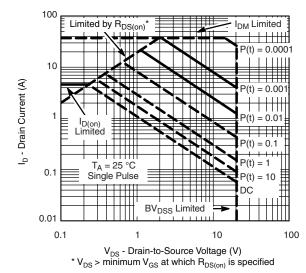
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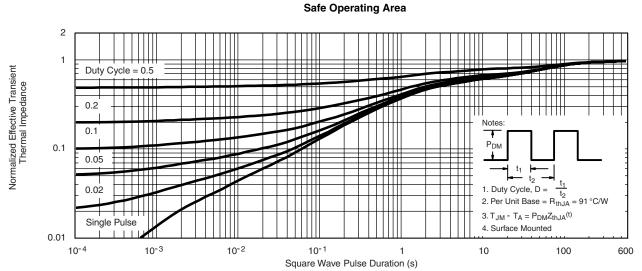
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TYPICAL CHARACTERISTICS 25 °C unless otherwise noted





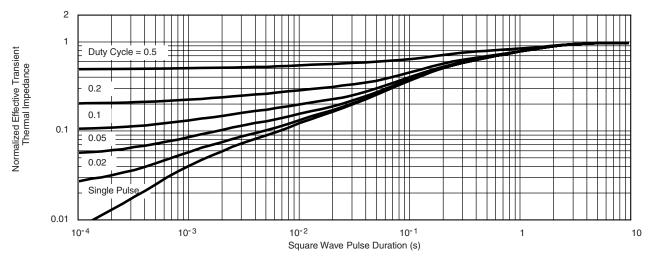




Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C unless otherwise noted



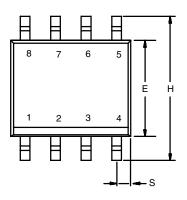
Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg272753.

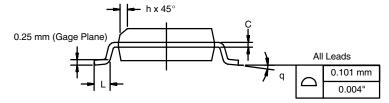
Document Number: 72753 S09-0704-Rev. B, 27-Apr-09



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INC	HES		
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I. 11-Sep-06						

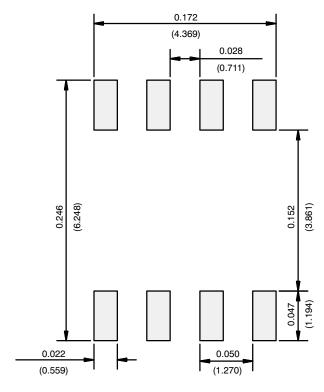
DWG: 5498

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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